LM9013G, LM9013H

Preferred Devices

Amplifier Transistors

NPN Silicon

• Moisture Sensitivity Level: 1

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	25	Vdc
Collector-Base Voltage	V _{CBO}	25	Vdc
Emitter-Base Voltage	V _{EBO}	3.0	Vdc
Collector Current – Continuous	۱ _C	1000	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	–55 to +150	°C

THERMAL CHARACTERISTICS

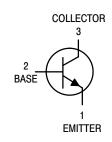
Characteristic	Symbol	Мах	Unit
Thermal Resistance, (Note 1.) Junction to Ambient	$R_{ hetaJA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{ extsf{ heta}JC}$	83.3	°C/W

1. $R_{\theta JA}$ is measured with the device soldered into a typical printed circuit board.



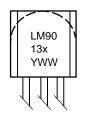
ON Semiconductor[™]

http://onsemi.com









LM9013x = Specific Device Code = G or H х Y

- = Year
- WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
LM9013G	TO-92	5000 Units/Box
LM9013H	TO-92	5000 Units/Box

Preferred devices are recommended choices for future use and best overall value.

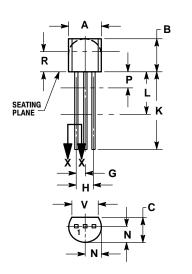
LM9013G, LM9013H

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage $(I_C = 10 \text{ mAdc}, I_B = 0)$		V _{(BR)CEO}	25	-	Vdc
Collector–Base Breakdown Voltage $(I_C = 10 \ \mu Adc, I_E = 0)$		V _{(BR)CBO}	25	-	Vdc
Emitter–Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$		V _{(BR)EBO}	3.0	-	Vdc
Collector Cutoff Current ($V_{CB} = 16 \text{ Vdc}, I_E = 0$)		I _{CBO}	-	0.5	μAdc
ON CHARACTERISTICS					
DC Current Gain (I _C = 50 mAdc, V _{CE} = 1.0 Vdc)	LM9013G LM9013H	h _{FE}	118 144	166 202	-
Collector–Emitter Saturation Voltage $(I_C = 250 \text{ mAdc}, I_B = 25 \text{ mAdc})$		V _{CE(sat)}	-	1.0	Vdc

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. CONTOUL OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	METERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
Ν	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
٧	0.135		3.43		

STYLE 1: PIN 1. EMITTER 2. BASE 3. COLLECTOR

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